

UP9972

Power MOSFET

60A, 60V N-CHANNEL
POWER MOSFET

■ DESCRIPTION

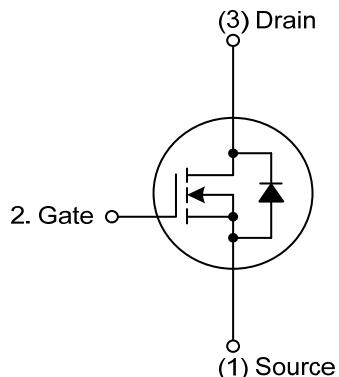
The UTC **UP9972** is an N-ch enhancement mode Power MOS Field Effect Transistor using advanced technology to provide fast speed switching, low on-resistance and perfect cost-effectiveness.

The UTC **UP9972** is ideal for commercial-industrial surface mount applications applied to DC/DC converters or other low voltage applications.

■ FEATURES

- * Single drive required
- * Fast switching capability
- * Ultra low gate charge
- * Halogen Free

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UP9972L-TN3-R	UP9972G-TN3-R	TO-252	G	D	S	Tape Reel
UP9972L-TN3-T	UP9972G-TN3-T	TO-252	G	D	S	Tube
UP9972L-TA3-T	UP9972G-TA3-T	TO-220	G	D	S	Tube

	(1)Packing Type	(1) T: Tube
	(2)Package Type	(2) TA3: TO-220, TN3: TO-252
	(3) Lead Plating	(3) G: Halogen Free, L: Lead Free



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V _{DSS}	60	V
Gate-Source Voltage	V _{GS}	±25	V
Continuous Drain Current (V _{GS} =10V, T _C =25°C)	I _D	60	A
Pulsed Drain Current (Note 2)	I _{DM}	230	A
Avalanche Current (Note 3)	I _{AR}	30	A
Single Pulse Avalanche Energy (Note 3)	E _{AS}	45	mJ
Power Dissipation (T _C =25°C)	P _D	54	W
		89	
Junction Temperature	T _J	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse width limited by T_{J(MAX)}

3. L = 100μH, V_{DD} =30V, I_{AS}=30A, R_G =25Ω, Starting T_J =25°C

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to ambient	θ _{JA}	160	°C/W
		62	
Junction to case	θ _{JC}	2.3	°C/W
		1.4	

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	60			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			10	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	1		3	V
Drain to Source On-state Resistance (Note)	R _{DS(ON)}	V _{GS} =10V, I _D =35A			18	mΩ
		V _{GS} =4.5V, I _D =25A			22	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		3170	5070	pF
Output Capacitance	C _{OSS}			280		pF
Reverse Transfer Capacitance	C _{RSS}			230		pF
Gate Resistance	R _G	f=1.0MHz		1.7		Ω
SWITCHING PARAMETERS						
Turn-ON Delay Time (Note)	t _{D(ON)}	V _{DS} =30V, V _{GS} =10V, I _D =35A R _G =3.3Ω, R _D =0.86Ω		11		ns
Turn-ON Rise Time	t _R			58		ns
Turn-OFF Delay Time	t _{D(OFF)}			45		ns
Turn-OFF Fall-Time	t _F			80		ns
Total Gate Charge (Note)	Q _G	I _D =35A, V _{DS} =48V, V _{GS} =4.5V		32	51	nC
Gate Source Charge	Q _{GS}			8		nC
Gate Drain Charge	Q _{GD}			20		nC



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■ ELECTRICAL CHARACTERISTICS(Cont.) ($T_J=25^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage (Note)	V_{SD}	$I_S=35A, V_{GS}=0V$			1.2	V
Reverse Recovery Time (Note)	t_{RR}	$I_S=35A, V_{GS}=0V$		50		ns
Reverse Recovery Charge	Q_{RR}	$dI/dt=100A/\mu s$		48		nC

Note: Pulse test

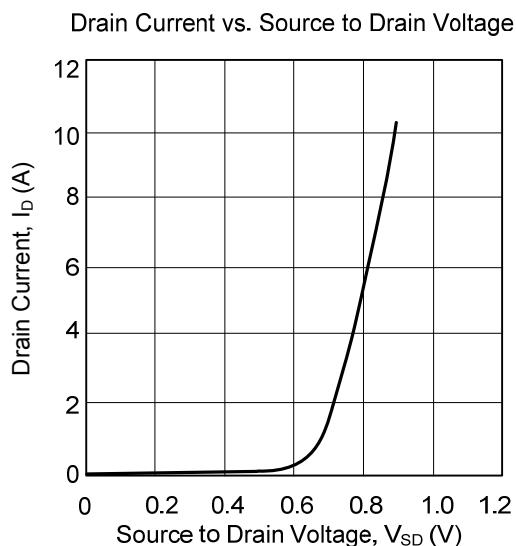
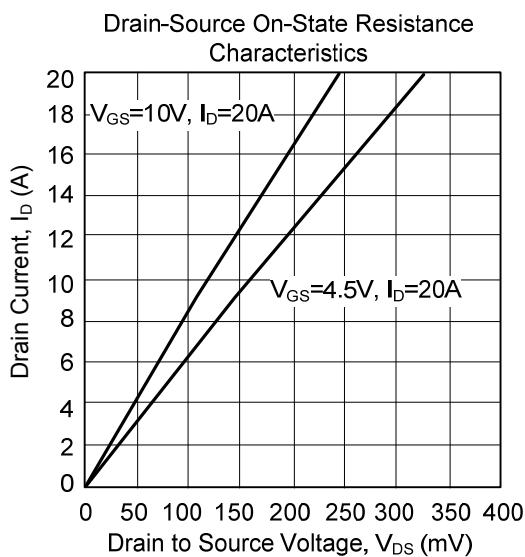
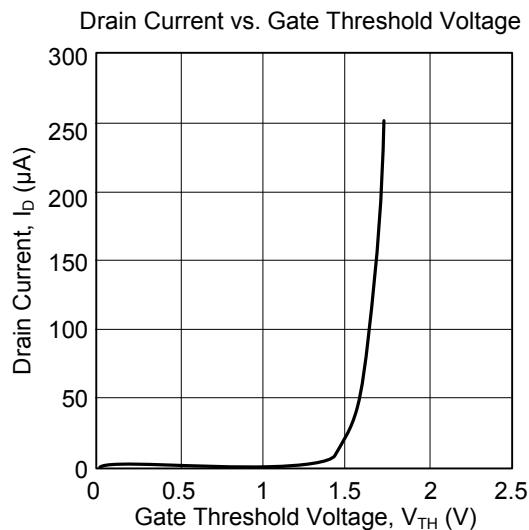
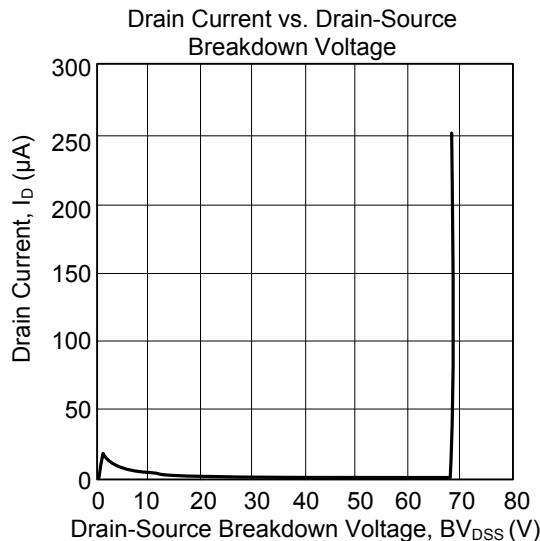


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■ TYPICAL CHARACTERISTICS



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